NSN 5961-01-321-1915

Transistor - Page 1 of 2



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Inclosure Material:
Metal Overall Langethy
Overall Length:
0.500 inches
Terminal Length:
0.312 inches
Overall Diameter: 1.250 inches
Mounting Facility Quantity:
1 Internal Configuration:
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-67
Mounting Method:
Threaded hole and terminal
Features Provided:
Hermetically sealed case
Thread Size:
0.190 inches
Semiconductor Material:
Germanium M. M. D. G. M. M. D. G. M. M. M. D. G. M.
Voltage Rating In Volts Per Characteristic:
70.0 breakdown voltage, collector-to-emitter, base open
Current Rating Per Characteristic:
10.00 amperes source cutoff current
Power Rating Per Characteristic:
70.0 watts small-signal input power, common-collector absolute
Transfer Ratio:
25.0 static forward current transfer ratio, common-emitter and 50.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 pin and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:

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NSN 5961-01-321-1915

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

A110a0